HD74HC4066

Quad Analog Switches/Quad Multiplexers

HITACHI

Description

This switch has low "on" resistance and low "off" leakage. It is a bidirectional switch, thus any analog input may be used as an output and vice-versa. Also the HD74HC4066 switch contains linearization circuitry which lowers the "on" resistance and increases switch linearity. The HD74HC4066 device allows control of up to 12 V (peak) analog signals with digital control signals of the same range. Each switch has its own control input which disables each switch when low.

Features

- High Speed Operation
- Wide Operating Voltage
- Low Quiescent Supply Current

Function Table

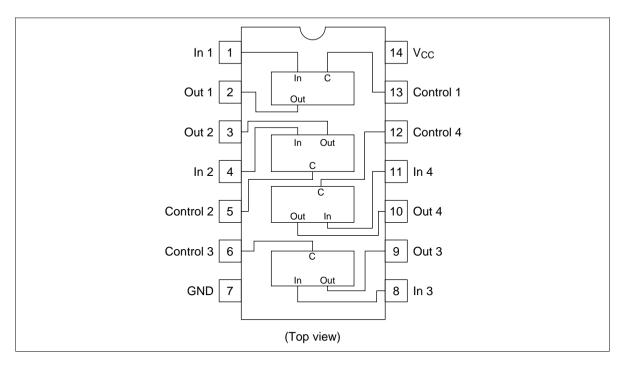
Control	Switch
L	OFF
Н	ON

GND \leq Vin \leq V_{CC} GND \leq Vout \leq V_{CC}

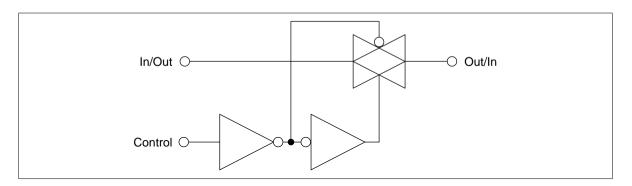


HD74HC4066

Pin Arrangement



Logic Diagram (1/4)



Absolute Maximum Ratings

Item		Symbol	Rating	Unit
Supply voltage		V _{cc}	-0.5 to +7.0	V
Control input voltage		V _{IN}	-0.5 to $V_{cc} + 0.5$	V
Switch I/O voltage) voltage		-0.5 to V_{cc} + 0.5	V
Supply current	(V _{cc})	I _{cc}	+50	mA
	(GND)	I _{GND}	- 50	mA
Switch I/O current (per pin)		I _{I/O}	±25	mA
Control input diode current		I _{IK}	±20	mA
Switch I/O diode current		I _{IOK}	±20	mA
Power dissipation		P _T	500	mW
Storage temperature rang	је	Tstg	-65 to +150	°C

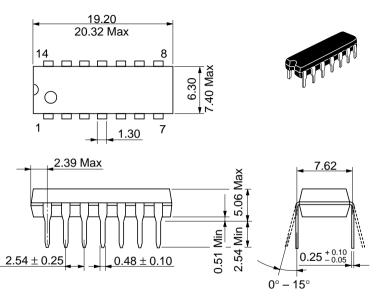
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DC Characteristics

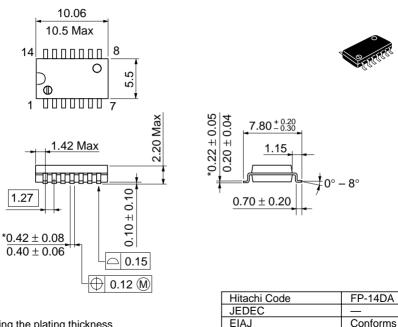
			Ta = 2	25°C		Ta = - +85°0	-40 to		
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Control input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V	
		4.5	3.15	_	_	3.15	_	_	
		6.0	4.2	_		4.2	_	_	
	V _{IL}	2.0	_	_	0.5	_	0.5	V	
		4.5	_	_	1.35	_	1.35	_	
		6.0		_	1.8	_	1.8	_	
"ON" resistance	R _{on}	2.0	_	2000	5000	_	6250	Ω	$V_C = V_{IH}$
		4.5		100	200	_	250	_	$Vin = 0 \text{ to } V_{CC}$
		6.0		60	170	_	210	_	lin/out = 1 mA
∆ON resistance	ΔR_{ON}	2.0	_	50	_	_	_	Ω	$V_C = V_{IH}$, $Iin/out = 1 mA$
between any two		4.5	_	3	_	_	_	_	between any two
channels		6.0	_	2		_	_	_	channels
OFF channel leakage current (switch off)	I _{S (OFF)}	6.0	_	_	±0.1	_	±1.0	μΑ	$\begin{aligned} &V_{\text{C}} = V_{\text{IL}} \\ &V_{\text{IN}} = V_{\text{CC}}, Vout = GND \\ &\text{or, } Vin = GND, \\ &Vout = V_{\text{CC}} \end{aligned}$
OFF channel leakage current (switch on)	I _{S (ON)}	6.0	_	_	±0.1	_	±1.0	μΑ	$V_{C} = V_{IH}$ Vin = V_{CC} or GND
Control input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V _{CC} or GND
Quiescent supply current	I _{cc}	6.0	_	_	1.0	_	10.0	μΑ	Vin = V _{CC} or GND

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

			Ta =	25°C		Ta = +85°(–40 to C		
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH}	2.0	_	_	50	_	65	ns	$R_L = 10 \text{ k}\Omega$
time	$t_{\scriptscriptstylePHT}$	4.5	_	4	10	_	13	=	
		6.0	_	_	9	_	11	=	
Output enable	t _{zH}	2.0	_	_	115	_	145	ns	$R_L = 1 \text{ k}\Omega$
time		4.5	_	10	23	_	29	_	
		6.0	_	_	20	_	25	_	
Output disable	t _{LZ}	2.0	_	_	115	_	145	ns	$R_L = 1 \text{ k}\Omega$
time	$t_{\scriptscriptstyle HZ}$	4.5	_	14	23	_	29	_	
		6.0	_	_	20	_	25	=	
Sine wave distortion		4.5	_	0.05	_	_	_	%	$R_{L} = 10 \text{ k}\Omega, C_{L} = 50 \text{ pF},$ $f_{IN} = 1 \text{ kHz}$
Band width (-3 dB)		4.5	_	30	_	_	_	MHz	$R_L = 600 \Omega, C_L = 50 pF,$ 20 log ₁₀ Vout/Vin = -3dB
Feedthrouth attenuation		4.5	_	-50	_	_	_	dB	$R_L = 600 \Omega, C_L = 50 pF,$ $f_{IN} = 1 MHz$
Cross talk between		2.0	_	25	_	_	_	mA	$R_L = 600 \Omega, C_L = 50 pF,$
control input to		4.5	_	60	_	_	_		$f_{IN} = 1 MHz$
signal I/O		6.0	_	75		_	_	_	
Cross talk between any two switches		4.5	_	-50	_	_	_	dB	$R_L = 600 \Omega, C_L = 50 pF,$ $f_{IN} = 1 MHz$
Maximum control		2.0	_	20	_	_	_	MHz	$R_L = 1 \text{ k}\Omega, C_L = 15 \text{ pF},$
frequency		4.5	_	30	_	_	_	_	$Vout = 1/2 (V_{CC})$
		6.0	_	30	_		_	_	
Control input capacitance	Cin		_	5	10	_	10	pF	
Switch I/O capacitance	Cin/out		_	6	_	_	_	pF	
Feed through capacitance	Cin/out		_	0.5	_	_	_	pF	
Power dissipation capacitance	C_{PD}		_	13	_	_	_	pF	



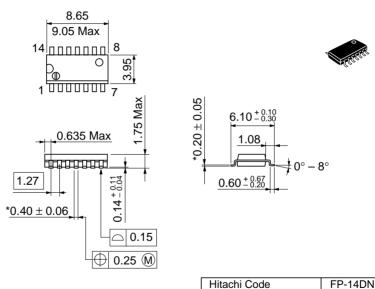
Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g



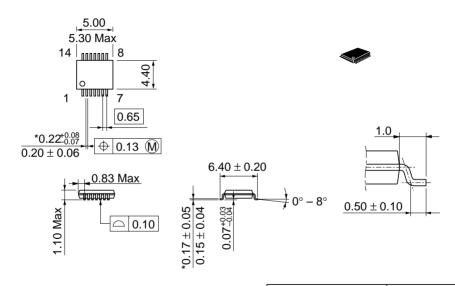
Weight (reference value)

0.23 g

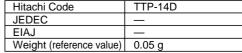
*Dimension including the plating thickness
Base material dimension



JEDEC Conforms EIAJ Conforms Weight (reference value) 0.13 g



*Dimension including the plating thickness
Base material dimension



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